FOC

Electro Optical Components, Inc.

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PbS near-infrared detector Multi-Pixel thin-film encapsulation



A brand of BASF – We create chemistry

Features

- Bondable electrode for COB mounting
- Very high sensitivity
- Suitable for automated wire-bonding
- Room temperature operation

Applications

- NIR spectroscopy
- Fire and spark detection
- Flame and moisture monitoring
- Gas detection

Electrical and optical characteristics per pixel

ĺ	Element	Peak wave-	20% cut-off	Peak D*		Time constant	Dark resistance R _D
	temperature	length λ₽	wavelength λ_{C}	(620 Hz, 1 Hz)		[µs]	[MΩ]
	[°C]	[µm]	[µm]	[cm·Hz½/W]			
		Тур.	Тур.	Тур.	Min.	Тур.	
ĺ	22	2.7	2.9	1 · 10 ¹¹	0.5 · 10 ¹¹	200	0.3 - 3

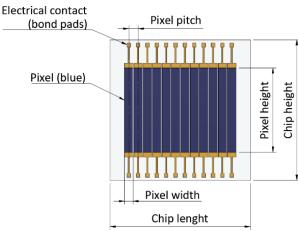
- Measured with 1550 nm LED, incident power 16 μW/cm²
- Measured in a voltage divider circuit with 50 V/mm
- Photo responsivity and detectivity are measured with constant load resistance ($R_L = 1 \text{ M}\Omega$) and calculated for matched resistance

Possible mechanical characteristics

•	Number of lines	1 - 4
•	Number of pixels	2 - 16
•	Minimum pixel width	20 μm
•	Minimum pixel height	20 μm
•	Minimum pixel pitch	50 μm
•	Minimal chip length	3000 μm
•	Minimal chip height	3000 μm

Please contact us for an individual design: info@hertzstueck.de





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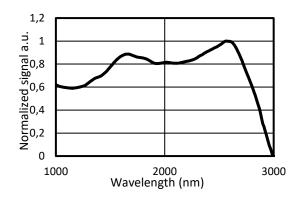


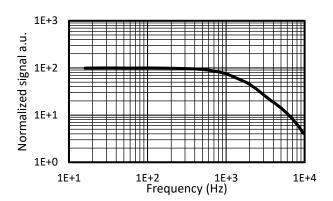
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Exemplary mechanical characteristics

Type No.	Number	Number	Pixel	Pixel	Pixel	Operating
	of lines	of pixels	pitch	width	height	temperature
			[µm]	[µm]	[µm]	[°C]
PbS_MP_01x12_0200_0180x1800	1	12	200	180	x 1800	-30 to +70

Typical spectral response per pixel Typical frequency response per pixel





Die attach

- Use clean, soft rubber tip for pick and place handling
- UV-curing is not suitable due to permanent damage by UV light exposure
- Element temperature should never exceed +70°C

Wire-bonding

- Electrodes are optimized for room temperature Al-wire-bonding
- Element temperature should never exceed +70°C

Options

- Individual housing
- Bonding onto PCB
- Integrated optics
- Evaluation-Kit available

Storage

- Storage temperature: -55°C to +70°C
- Exposure to UV light results in permanent damage
- Prevent exposure to UV and visible light

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Handling

- Active area is scratch sensitive, protect top surface from any mechanical contact
- Ensure dust-free environment for device handling
- Operating temperature: -30°C to +70°C

Regulatory

For the use of Hertzstück™ PbS and PbSe infrared photodetectors in medical devices, monitoring and control instruments and consumer applications RoHS exemptions apply.

For automotive applications Hertzstück™ PbS and PbSe infrared photodetectors fall under ELV exemption.